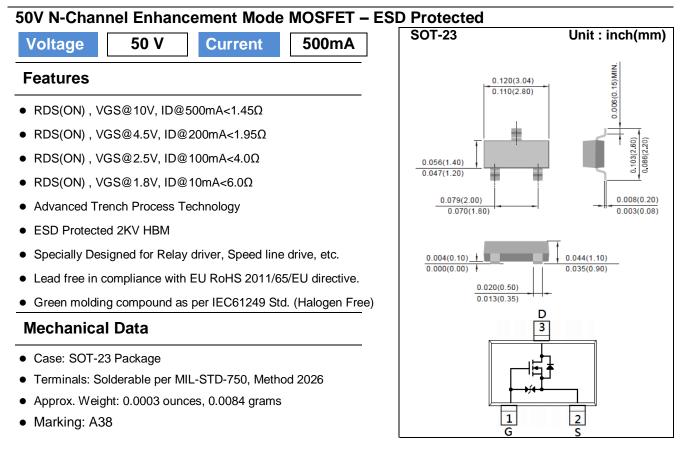
| ΡΛΝ | ĴΪΤ |
|-----|-------------------|
| | SEMI CONDUCTOR |



Maximum Ratings and Thermal Characteristics (T_A=25[°]C unless otherwise noted)

| PARAMETER | | SYMBOL | LIMIT | UNITS |
|---|----------------------|----------------------------------|---------|-------|
| Drain-Source Voltage | | V _{DS} | 50 | V |
| Gate-Source Voltage | V _{GS} | <u>+</u> 20 | V | |
| Continuous Drain Current | | I _D | 500 | mA |
| Pulsed Drain Current | | I _{DM} | 1200 | mA |
| Power Dissipation | T _A =25°C | P _D | 500 | mW |
| | Derate above 25°C | | 4 | mW/°C |
| Operating Junction and Storage Temperature Range | | T _J ,T _{STG} | -55~150 | °C |
| Typical Thermal resistance - Junction to Ambient ^(Note 3) | | R _{eja} | 250 | °C/W |



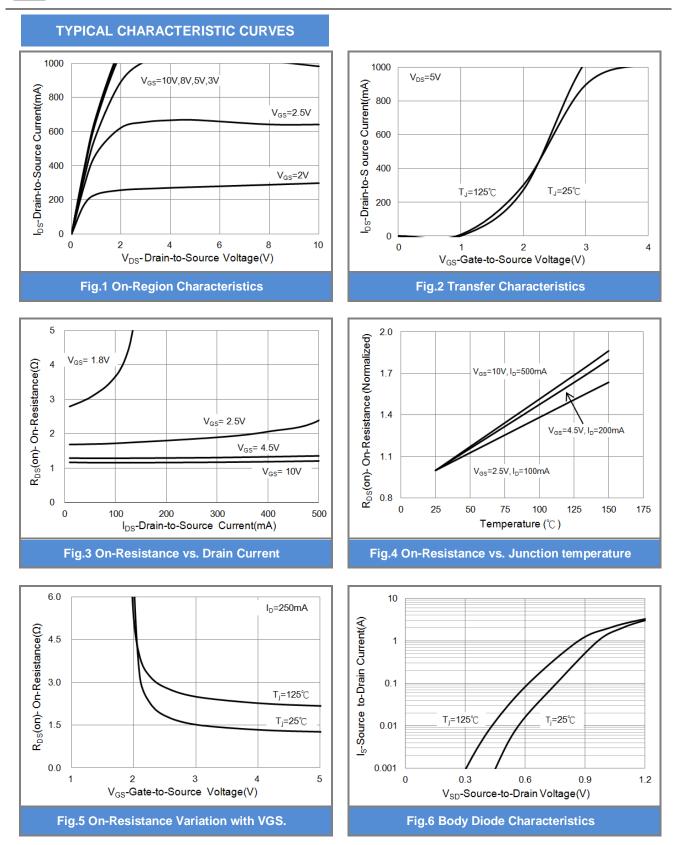
Electrical Characteristics (T_A=25°C unless otherwise noted)

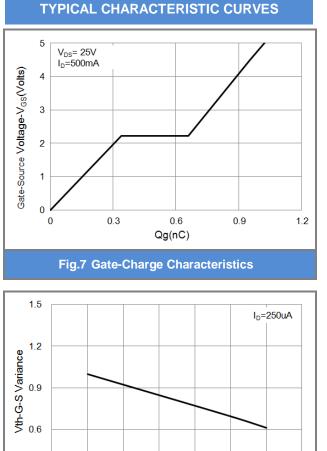
| PARAMETER | SYMBOL | TEST CONDITION | MIN. | TYP. | MAX. | UNITS |
|----------------------------------|---------------------|---|------|------|-------------|-------|
| Static | | | | | | |
| Drain-Source Breakdown Voltage | BV_{DSS} | V _{GS} =0V,I _D =250uA | 50 | - | - | V |
| Gate Threshold Voltage | V _{GS(th)} | $V_{DS}=V_{GS}$, $I_{D}=250$ uA | 0.5 | 0.86 | 1.0 | V |
| Drain-Source On-State Resistance | R _{DS(on)} | V_{GS} =10V,I _D =500mA | - | 1.2 | 1.45 | Ω |
| | | V_{GS} =4.5V,I _D =200mA | - | 1.3 | 1.95 | |
| | | V _{GS} =2.5V,I _D =100mA | - | 1.7 | 4.0 | |
| | | V _{GS} =1.8V,I _D =10mA | - | 4.0 | 6.0 | |
| Zero Gate Voltage Drain Current | I _{DSS} | V _{DS} =50V,V _{GS} =0V | - | - | 1 | uA |
| Gate-Source Leakage Current | I _{GSS} | V _{GS} = <u>+</u> 20V,V _{DS} =0V | - | - | <u>+</u> 10 | uA |
| Dynamic (Note 4) | | | | | | |
| Total Gate Charge | Qg | V _{DS} =25V, I _D =500mA, V _{GS} =4.5V | - | 0.95 | - | nC |
| Gate-Source Charge | Q _{gs} | | - | 0.34 | - | |
| Gate-Drain Charge | Q _{gd} | | - | 0.32 | - | |
| Input Capacitance | Ciss | V _{DS} =25V, V _{GS} =0V, f=1.0MHZ | - | 36 | - | |
| Output Capacitance | Coss | | - | 11 | - | pF |
| Reverse Transfer Capacitance | Crss | | - | 6.6 | - | |
| Turn-On Delay Time | td _(on) | | - | 2.3 | - | |
| Turn-On Rise Time | tr | $V_{DD}=25V, I_{D}=500mA,$ | - | 20 | - | ns |
| Turn-Off Delay Time | td _(off) | $V_{GS}=10V,$ $R_G=6\Omega^{(Note 1,2)}$ | - | 7 | - | |
| Turn-Off Fall Time | tf | R _G =012 | - | 20 | - | |
| Drain-Source Diode | | | | | | |
| Maximum Continuous Drain-Source | | | | | 500 | mA |
| Diode Forward Current | I _S | | - | - | 500 | IIIA |
| Diode Forward Voltage | V_{SD} | I _S =500mA, V _{GS} =0V | - | 0.9 | 1.5 | V |

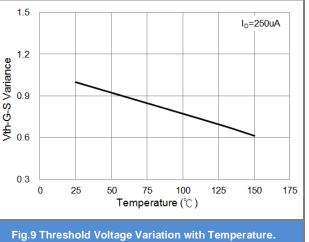
NOTES :

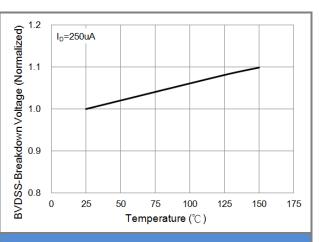
- 1. Pulse width</br>
- 2. Essentially independent of operating temperature typical characteristics.
- 3. R_{0JA} is the sum of the junction-to-case and case-to-ambient thermal resistance where the case thermal reference is defined as the solder mounting surface of the drain pins. mounted on a 1 inch square pad of copper
- 4. Guaranteed by design, not subject to production testing













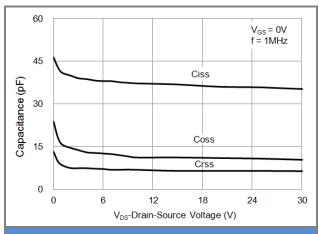


Fig.10 Capacitance vs. Drain-Source Voltage.

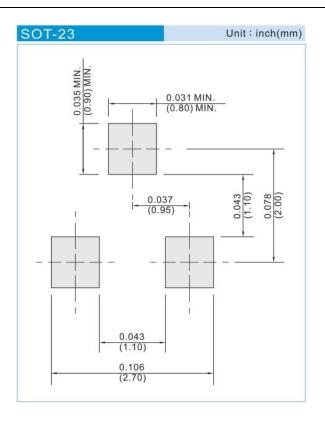




PART NO PACKING CODE VERSION

| PART NO PACKING CODE | Package Type | Packing type | Marking | Version |
|----------------------|--------------|--------------------|---------|--------------|
| PJA3438_R1_00001 | SOT-23 | 3K pcs / 7" reel | A38 | Halogen free |
| PJA3438_R2_00001 | SOT-23 | 12K pcs / 13" reel | A38 | Halogen free |

MOUNTING PAD LAYOUT







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